# *Ab initio* Calculations of YAlO<sub>3</sub> and ABO<sub>3</sub> Perovskite (001), (011) and (111) Surfaces, Interfaces and Defects

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*Abstract*—We performed first-principles calculations for technologically most important ABO<sub>3</sub> perovskites, such as, CaTiO<sub>3</sub>, SrTiO<sub>3</sub>, PbTiO<sub>3</sub>, BaTiO<sub>3</sub>, SrZrO<sub>3</sub> and PbZrO<sub>3</sub> (001), (011) and (111) surfaces, interfaces and bulk *F*-centers. For ABO<sub>3</sub> perovskite neutral (001) surfaces, in most cases, all upper surface layer atoms relax inward, whereas the all second surface layer atoms relax outward, and again, all third surface layer atoms relax inward. The relaxation pattern for YAIO<sub>3</sub> charged (001) surfaces is quite different from ABO<sub>3</sub> perovskite neutral (001) surfaces. The ABO<sub>3</sub> perovskite (001) surface energies are almost equal for both AO and BO<sub>2</sub>-terminations, and always considerably smaller than the (011) and especially (111) surface energies. Systematic trends in BaTiO<sub>3</sub>, SrTiO<sub>3</sub>, SrZrO<sub>3</sub> and PbZrO<sub>3</sub> bulk *F*-center calculations are analyzed.

Index Terms—YAlO<sub>3</sub>; ABO<sub>3</sub> perovskites; B3LYP; B3PW; surfaces

## I. INTRODUCTION

Surface and interface phenomena, taking place in the ABO<sub>3</sub> perovskites as well as their nanostructures, the complex nature of their surface and interface states, the novel mechanisms of surface electronic processes are the key topics in nowadays solid state physics [1-7]. CaTiO<sub>3</sub> (CTO), SrTiO<sub>3</sub> (STO), PbTiO<sub>3</sub> (PTO), BaTiO<sub>3</sub> (BTO), SrZrO<sub>3</sub> (SZO) and PbZrO<sub>3</sub> (PZO) materials are so-called ABO<sub>3</sub> perovskites, and they have a large amount of technologically important applications, such as, for example, capacitors, actuators, and charge storage devices, and many others [8], for which the surface quality and structure are essential. This is the main reason, why in the last twenty-five years ABO<sub>3</sub> perovskite (001) surfaces were worldwide intensively explored both experimentally and theoretically [9-21]. At the ab initio level, it is much more difficult to calculate the ABO3 perovskite very complex, charged and polar (011) [11-13, 21-26] and (111) surfaces [27-31], than the neutral (001) surfaces [9-21].

Logical next step, after the ABO<sub>3</sub> perovskite (001), (011) and (111) surface theoretical investigations, is to calculate interfaces between the two ABO<sub>3</sub> perovskites. The further development of ABO<sub>3</sub> perovskite (001) interfaces is a highly promising research direction due to potential nanoscale device

applications. Taking into account the enormous technological potential of ABO<sub>3</sub> perovskites as well as numerous first principles calculations of their (001) surfaces [11-21], it is difficult to understand why only a small amount of experimental and *ab initio* studies exist dealing with BaTiO<sub>3</sub>/SrTiO<sub>3</sub>, SrZrO<sub>3</sub>/PbZrO<sub>3</sub> and PbTiO<sub>3</sub>/SrTiO<sub>3</sub> (001) interfaces [32-36].

It is worth to notice, that all properties of the industrially important ABO<sub>3</sub> perovskites are affected by the defects, for example, by oxygen vacancies. Oxygen vacancy ( $V_0$ ) (so-called neutral *F*-center) in ABO<sub>3</sub> perovskites traps two electrons. Experimental and theoretical investigations of *F*-centres in complex ABO<sub>3</sub> matrixes are a very important topic, since the *F*-center is the best known classical point defect, which strongly affects all material properties [37-44].

## II. COMPUTATIONAL METHOD

We performed our *ab initio* calculations for ABO<sub>3</sub> perovskite and YAIO<sub>3</sub> (YAO) surfaces using the hybrid exchange-correlation functionals B3PW [45] or B3LYP [46] as well as the world well known CRYSTAL computer code [47]. The strong side of the CRYSTAL computer code is possibility to perform *ab initio* calculations for isolated two-dimensional slabs perpendicular to the ABO<sub>3</sub> perovskite surface, without any artificial periodicity in the *z* direction.

For example, for calculations of ABO<sub>3</sub> perovskite and YAlO<sub>3</sub> (001) surfaces, we used symmetrical slabs consisting of nine alternating neutral AO and BO<sub>2</sub> (in case of ABO<sub>3</sub> perovskites), or charged YO and AlO<sub>2</sub> (in case of YAlO<sub>3</sub>) layers. In case of ABO<sub>3</sub> perovskites, our first slab was terminated by AO planes from both slab sides and consisted of a supercell which contained 22 atoms. The second slab, in case of ABO<sub>3</sub> perovskites, was terminated from both sides by BO<sub>2</sub>-planes and consisted from a supercell containing 23 atoms. Both AO and BO<sub>2</sub>-terminated slabs were non-stoichiometric, with their unit cell equations  $A_5B_4O_{13}$  and  $A_4B_5O_{14}$ . Since supercell in our calculations should be neutral, we used a basis sets for neutral Y, Al and O atoms [47] in our YAlO<sub>3</sub> (001) surface calculations. Calculation details for ABO<sub>3</sub> perovskite

polar (011) and (111) surfaces are described by us in references [11-13, 21-31].

We have used the same model for modelling of BaTiO<sub>3</sub>/SrTiO<sub>3</sub>, SrZrO<sub>3</sub>/PbZrO<sub>3</sub> and PbTiO<sub>3</sub>/SrTiO<sub>3</sub> (001) interfaces [34-36]. For example, calculations of the BaTiO<sub>3</sub>/SrTiO<sub>3</sub> (001) interfaces were carried out using the symmetrically terminated slab model. The SrTiO<sub>3</sub> substrate contained 11 atomic monolayers and was terminated by the TiO<sub>2</sub> monolayer from both substrate sides. Next, monolayer by monolayer epitaxial growth was modelled by adding a pair of BaTiO<sub>3</sub> (001) monolayers symmetrically to both sides of a SrTiO<sub>3</sub> substrate slab [34-36]. Finally, the ABO<sub>3</sub> perovskite, or for example, the BaTiO<sub>3</sub> bulk *F*-center calculations were carried out using 3 x 3 x 3 times extended supercell model. Such a supercell in our calculations contains 134 atoms as well as one isolated *F*-center defect [38,40,43].

#### **III. FIRST-PRINCIPLES CALCULATIONS OF SURFACES**

As a first step of our calculations, we calculated the ABO<sub>3</sub> perovskite and YAO bulk lattice constants [2]. Using the B3PW hybrid exchange-correlation functional, we calculated the STO (3.904Å), BTO (4.008Å), PTO (3.936Å), and CTO (3.851Å) as well as using the hybrid B3LYP exchange-correlation functional the SZO (4.195Å), PZO (4.220Å), and YAO (3.712Å) cubic bulk lattice constants. We used calculated cubic bulk lattice constants in all our future calculations.

TABLE I. OUR CALCULATED RELAXATION OF ATOMS (IN PERCENT OF BULK LATTICE CONSTANT) FOR CTO, BTO, SZO, PZO PEROVSKITES AS WELL AS YAO.

	СТО	BTO	SZO	PZO	YAO
nin.	CaO	BaO	SrO	PbO	YO
Ion	B3PW	B3PW	B3LYP	B3LYP	B3LYP
Α	-8.31	-1.99	-7.63	-5.69	-9.16
0	-0.42	-0.63	-0.86	-2.37	1.89
В	1.12	1.74	0.86	0.57	-0.32
0	0.01	1.40	-0.05	0.09	-0.20
Α	-	-	-1.53	-0.47	-3.34
0	-	-	-0.45	-0.47	-0.03
nin.	TiO <sub>2</sub>	TiO <sub>2</sub>	ZrO <sub>2</sub>	ZrO <sub>2</sub>	AlO <sub>2</sub>
В	-1.71	-3.08	-1.38	-2.37	-0.23
0	-0.10	-0.35	-2.10	-1.99	-0.55
А	2.75	2.51	2.81	4.36	0.48
0	1.05	0.38	0.91	1.04	0.10
В	-	-	-0.04	-0.47	0.00
0	-	-	-0.05	-0.28	-0.01
	Inin. Ion A O B O A O A O B O A O B O A O B O A O B O A O B O A O B O A O B O A O B O A O B O A O O A O O A O O A O O A O O A A O A A A A A A A A A A A A A	$\begin{array}{c c} & CTO \\ \hline \text{in.} & CaO \\ \hline \text{Ion} & B3PW \\ \hline A & -8.31 \\ \hline O & -0.42 \\ \hline B & 1.12 \\ \hline O & 0.01 \\ \hline A & - \\ \hline O & 0.01 \\ \hline A & - \\ \hline O & - \\ \hline \text{nin.} & TiO_2 \\ \hline B & -1.71 \\ \hline O & -0.10 \\ \hline A & 2.75 \\ \hline O & 1.05 \\ \hline B & - \\ \hline O & - \\ \hline O & - \\ \hline \end{array}$	CTO BTO   iin. CaO BaO   Ion B3PW B3PW   A -8.31 -1.99   O -0.42 -0.63   B 1.12 1.74   O 0.01 1.40   A - -   O 0.01 1.40   A - -   O - -   O - -   nin. TiO2 TiO2   B -1.71 -3.08   O -0.10 -0.35   A 2.75 2.51   O 1.05 0.38   B - -   O - -	$\begin{array}{c c c c c c c c c c c c c c c c c c c $	CTO BTO SZO PZO   iin. CaO BaO SrO PbO   Ion B3PW B3PW B3LYP B3LYP   A -8.31 -1.99 -7.63 -5.69   O -0.42 -0.63 -0.86 -2.37   B 1.12 1.74 0.86 0.57   O 0.01 1.40 -0.05 0.09   A - - -1.53 -0.47   O - - -0.45 -0.47   nin. TiO2 TiO2 ZrO2 ZrO2   B -1.71 -3.08 -1.38 -2.37   O -0.10 -0.35 -2.10 -1.99   A 2.75 2.51 2.81 4.36   O 1.05 0.38 0.91 1.04   B - - -0.05 -0.28

As a next step of our calculations, we performed upper three layer atom relaxation for neutral AO and  $\mathrm{BO}_2$ -terminated

ABO<sub>3</sub> perovskite (001) surfaces as well as charged YO and AlO<sub>2</sub>-terminated YAlO<sub>3</sub> (001) surfaces (Table I). In the case of ABO<sub>3</sub> perovskites, all upper layer atoms for both terminations relax inwards, all second layer atoms, with the single exception of second layer O atom for SrO-terminated SZO (001) surface, outwards, and all third layer atoms for both terminations, again, relax inwards [2]. The relaxation pattern for charged YO and AlO<sub>2</sub>-terminated YAlO<sub>3</sub> (001) surfaces is quite different from neutral ABO<sub>3</sub> perovskite (001) surface relaxation pattern.

TABLE II. OUR CALCULATED SURFACE ENERGIES (IN EV PER SURFACE CELL).

Crystal	СТО	BTO	SZO	PZO		
Termination	Surface energies for (001) surfaces					
AO	0.94	1.19	1.13	1.00		
BO <sub>2</sub>	1.13	1.07	1.24	0.93		
	Surface energies for (011) surfaces					
BO	3.13	2.04	3.61	1.89		
А	1.91	3.24	2.21	1.74		
0	1.86	1.72	2.23	1.85		
	Surface energies for (111) surfaces					
AO <sub>3</sub>	5.86	8.40	9.45	8.21		
В	4.18	7.28	7.98	6.93		

As we can see from Table II, our calculated ABO<sub>3</sub> perovskite neutral (001) surface energies for both AO and BO<sub>2</sub>terminations are almost equal, whereas polar (011) and (111) surface energies for different surface terminations are quite different. It is worth to notice, that the polar (111) surface energies, independently from termination, always are considerably larger than the polar (011) surface energies, but polar (011) surface energies are always larger than the (001) surface energies.

## **IV.FIRST-PRINCIPLES CALCULATIONS OF INTERFACES**

performed ab initio studies We dealing with BaTiO<sub>3</sub>/SrTiO<sub>3</sub>, SrZrO<sub>3</sub>/PbZrO<sub>3</sub> and PbTiO<sub>3</sub>/SrTiO<sub>3</sub> (001) interfaces [34-36]. As example we will analyze BaTiO<sub>3</sub>/SrTiO<sub>3</sub> (001) interface. We used as a substrate 11 layer thick symmetrical SrTiO<sub>3</sub> (001) slab from both sides terminated with TiO<sub>2</sub> (001) surfaces and augmented to both sides of this substrate BaO-terminated BaTiO<sub>3</sub> slab. The band gap of this our 13-layers containing system is equal to 3.47 eV. If we add to the SrTiO<sub>3</sub> (001) substrate from both sides 3, 5, 7 or 9 BaOterminated layers, the band gap of our system is equal to 3.29, 3.25, 3.24 and 3.22 eV. So, the BaTiO<sub>3</sub>/SrTiO<sub>3</sub> interface band gap rather slowly decrease with the number of layers from 3.47 eV (1 augmented BaO-terminated layer from both sides) till 3.22 eV (9 augmented BaO-terminated BaTiO<sub>3</sub> layers augmented from both sides on SrTiO<sub>3</sub> substrate). If we augment on SrTiO<sub>3</sub> (001) slab from both sides 2, 4, 6, 8 or 10 TiO<sub>2</sub>-terminated BaTiO<sub>3</sub> (001) layers, the interface band gap is equal to 2.33, 2.16, 2.10, 2.06 and 2.06 eV.

# V.FIRST-PRINCIPLES CALCULATIONS OF DEFECTS

Our B3PW calculated nearest atom displacements surrounding the *F*-center in ABO<sub>3</sub> perovskites are collected in Table III and compared with related results obtained for other ABO<sub>3</sub> perovskites [38-41, 43].

Bulk <i>F</i> -center	BTO	STO	SZO	PZO
F-center charge, e	-1.103	-1.1	-1.25	-0.68
F under CB, eV	0.23	0.69	1.12	1.72
Form. energy, eV	10.3	7.1	7.55	7.25
B relax., % of $a_0$	1.06	7.76	3.68	0.48
O relax., % of $a_0$	-0.71	-7.79	-2.63	-
A relax., % of $a_0$	-0.08	3.94	0.46	-5.99

TABLE III. CALCULATED BULK F-CENTER MAIN CHARACTERISTICS.

As we can see from Table III, the two nearest to the *F*-center Ti atoms are by 1.06% of  $a_0$  repulsed in the BaTiO<sub>3</sub> from the oxygen vacancy. Also in another ABO<sub>3</sub> perovskites, such as SrTiO<sub>3</sub>, SrZrO<sub>3</sub> and PbZrO<sub>3</sub>, B atoms are repulsed from the oxygen vacancy by 7.76, 3.68 and 0.48 % of  $a_0$ . In contrast, the second nearest O atoms in the ABO<sub>3</sub> perovskites always are attracted towards the *F*-center by 0.71, 7.79 and 2.63 % of  $a_0$  in the BaTiO<sub>3</sub>, SrTiO<sub>3</sub> and SrZrO<sub>3</sub>.

Inside the oxygen vacancy in BaTiO<sub>3</sub>, SrTiO<sub>3</sub>, SrZrO<sub>3</sub> and PbZrO<sub>3</sub> are located -1.103*e*, -1.1*e*, -1.25*e* and -0.68*e* of additional charge. The *F*-center formation energy for ABO<sub>3</sub> perovskites are in the range between 7 and 10 eV. For example, the calculated BaTiO<sub>3</sub>, SrTiO<sub>3</sub>, SrZrO<sub>3</sub> and PbZrO<sub>3</sub> formation energies are equal to 10.3, 7.1, 7.55 and 7.25 eV. The *F*-center defect induced levels in the band gap of ABO<sub>3</sub> perovskites are located more close to the conduction band bottom, than the valence band top. For example, the *F*-center defect induced 0.23, 0.69, 1.12 and 1.72 eV below the conduction band bottom in the BaTiO<sub>3</sub>, SrTiO<sub>3</sub>, SrZrO<sub>3</sub> and PbZrO<sub>3</sub> perovskites.

## CONCLUSIONS

ABO<sub>3</sub> perovskite neutral (001) surface upper layer atoms, with a few exceptions, relax inwards, second layer atoms upwards, and third layer atoms, again, inwards. Relaxation pattern for YAlO<sub>3</sub> charged (001) surfaces is quite different from ABO<sub>3</sub> perovskite neutral (001) surfaces. The ABO<sub>3</sub> perovskite (001) surface energies for both possible terminations AO and BO<sub>2</sub> are almost similar. The ABO<sub>3</sub> perovskite polar (111) surface energies are considerably larger than the polar (011) surface energies. The neutral ABO<sub>3</sub> perovskite (001) surface energies always are smaller than the polar (011) and especially (111) surface energies. The BaTiO<sub>3</sub>/SrTiO<sub>3</sub>, SrZrO<sub>3</sub>/PbZrO<sub>3</sub> and PbTiO<sub>3</sub>/SrTiO<sub>3</sub> (001) interface band gap depends much more strongly from the termination of the upper augmented layer (AO or BO<sub>2</sub>) than from the number of augmented layers. Results of our calculations for the classical point defect F-center in ABO<sub>3</sub> perovskites are presented, and systematic trends, common for *F*-center defects in ABO<sub>3</sub> perovskites are analyzed.

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